

02/28/02
JC903 U.S. PTO

03-01-02

Attorney Docket No. AMDI:115HON

UTILITY PATENT APPLICATION TRANSMISSION

Assistant Commissioner For Patents
Washington, D.C. 20231

Sir:

Transmitted herewith for filing is the patent application of:

Inventor(s): Andy Wei, Akif Sultan and David Wu

For: **SOI MOSFET JUNCTION
DEGRADATION USING MULTIPLE
BURIED AMORPHOUS LAYERS**

Enclosed are

<input checked="" type="checkbox"/>	A specification consisting of: a 11 page disclosure; 5 page(s) of claims, and an abstract of the disclosure
<input checked="" type="checkbox"/>	Two (2) Declarations/Powers of Attorney
<input checked="" type="checkbox"/>	6 sheets of informal drawings; and 2 duplicate sets thereof
<input checked="" type="checkbox"/>	Two (2) Assignments of the invention to: Advanced Micro Devices, Inc.
<input checked="" type="checkbox"/>	Other Two (2) PTO Form 1595's and one (1) copy of each; Two Return Postcards; PTO/SB/35

CLAIMS AS FILED

Total Claims 33	$-20 = 13$	$\times \$ 18 = 234$
Independent Claims 5	$-3 = 2$	$\times \$ 84 = 168$
Multiple Dependent Claims Presented 0		$\times \$ 280 = 0$
Basic Fee		\$ 740
Recording Fee for Assignment		\$ 40
TOTAL FILING FEE:		\$ 1182

The Assistant Commissioner is authorized to charge the total filing fee to deposit account number 01-0365, Order No. AMDI:115HON. If the fee is incorrect, the Assistant Commissioner is authorized to charge said deposit account for the correct the filing fee amount. Two duplicate copies of this sheet are enclosed.

The Assistant Commissioner is authorized to charge any fees incurred under 37 C.F.R. 1.17 or credit any overpayment during the pendency of this application to the above listed deposit account.

Please address all correspondence in connection with this application to: Timothy M. Honeycutt, Attorney at Law, P.O. Box 1577, Cypress, Texas 77410-1577, Telephone (281) 379-7999.

Date: 2/28/02



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PATENT TRADEMARK OFFICE

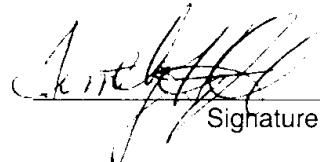
TT4972

REQUEST AND CERTIFICATION UNDER 35 U.S.C. 122(b)(2)(B)(i)		First Named Inventor Andy Wei
Title SOI MOSFET JUNCTION DEGRADATION USING MULTIPLE BURIED AMORPHOUS LAYERS		
Atty Docket Number AMDI:115\HON		

I hereby certify that the invention disclosed in the attached application **has not and will not be** the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing. I hereby request that the attached application not be published under 35 U.S.C. 122(b).

2/28/02

Date



Signature

Timothy M. Honeycutt

Typed or printed name

This request must be signed in compliance with 37 CFR 1.33(b) and submitted with the application **upon filing**.

Applicant may rescind this nonpublication request at any time. If applicant rescinds a request that an application not be published under 35 U.S.C. 122(b), the application will be scheduled for publication at eighteen months from the earliest claimed filing date for which a benefit is claimed.

If applicant subsequently files an application directed to the invention disclosed in the attached application in another country, or under a multilateral international agreement, that requires publication of applications eighteen months after filing, the applicant **must** notify the United States Patent and Trademark Office of such filing within forty-five (45) days after the date of the filing of such foreign or international application. **Failure to do so will result in abandonment of this application (35 U.S.C. 122(b)(2)(B)(iii)).**

Burden Hour Statement: This collection of information is required by 37 CFR 1.213(a). The information is used by the public to request that an application not be published under 35 U.S.C. 122(b) (and the PTO to process that request). Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This form is estimated to take 6 minutes to complete. This time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.